TOSHIBA **TLP863**

TOSHIBA PHOTOINTERRUPTER INFRARED + PHOTODARLINGTONTRANSISTOR

TLP863

VCR, COMPACT DISC PLAYER

COPYING MACHINE, FACSIMILE, PRINTER VENDING MACHINE, TICKETING MACHINE FOR VARIOUS POSITION DETECTION

The TLP863 is a photointerrupter combining GaAs infrared LED with high sensitivity Si photodarlingtontransistor. The TLP863 has a high current transfer ratio, can be driven by low input current and is best suited to a low power circuit.

Because of the oblong detection slit, this phototransistor is best suited to the upward-downward position detection.

- Small package
- Printed wiring board direct mounting type (with a locating pin)

Gap : 2.2mm

High resolution : Slit width

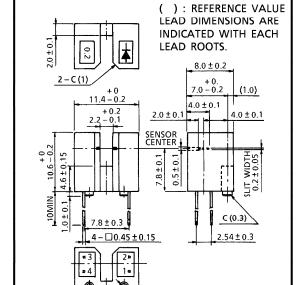
0.2mm (the oblong slit)

High current transfer ratio: IC/IF=25% (min) at

 $I_{\rm F} = 1 \, \rm mA$

The detector side is of visible light cut type.

Material of the package : Polycarbonate



11-11B1

Unit in mm

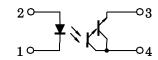
Weight: 0.9g (typ.)

PIN CONNECTION

JEDEC

TOSHIBA

EIAJ



- 1. CATHODE
- 2. ANODE
- 3. EMITTER
- 4. COLLECTOR

961001EBC2

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Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.

The products described in this document are subject to foreign exchange and foreign trade control laws.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of TOSHIBA CORPORATION or others.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
LED	Forward Current	$I_{\mathbf{F}}$	50	mA	
	Forward Current Derating (Ta>25°C)	$\Delta I_{\mathbf{F}}/^{\circ}\mathbf{C}$	-0.33	mA/°C	
	Reverse Voltage	$v_{ m R}$	5	V	
	Collector-Emitter Voltage	v_{CEO}	30	V	
OR.	Emitter-Collector Voltage	v_{ECO}	5	V	
3CT	Collector Power Dissipation	$P_{\mathbf{C}}$	75	mW	
DETECTOR	Collector Power Dissipation Derating (Ta>25°C)	△P _C /°C	-1	mW/°C	
	Collector Current	$I_{\mathbb{C}}$	40	mA	
Operating Temperature Range		$T_{ m opr}$	-25~85	°C	
Storage Temperature Range		${ m T_{stg}}$	-40~100	°C	
Soldering Temperature (5s)		T_{sol}	260	°C	

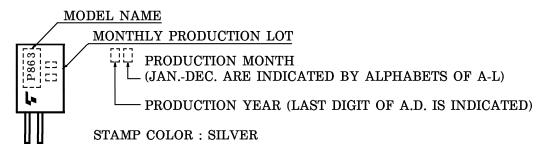
RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	v_{CC}		5	16	V
Forward Current	${ m I_F}$			20	mA
Operating Temperature	$T_{ m opr}$	-10		70	$^{\circ}\mathrm{C}$

OPTO-ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	Forward Voltage	$v_{\mathbf{F}}$	$I_{ m F} = 10 { m mA}$	1.00	1.15	1.30	V
LED	Reverse Current	$I_{ m R}$	$V_R = 5V$	_	_	10	μ A
LED	Peak Emission Wavelength	$\lambda_{\mathbf{P}}$	$I_{ m F} = 10 { m mA}$	_	940	_	nm
	Dark Current	$I_{D}(I_{CEO})$	$V_{CE} = 16V, I_{F} = 0$	_	_	0.25	μ A
DETECTOR	Peak Sensitivity Wavelength	$\lambda_{\mathbf{P}}$	_		870		nm
	Current Transfer Ratio	I_C/I_F	$V_{CE}=2V, I_F=1mA$	25	_	1000	%
COUPLED	Collector-Emitter Saturation Voltage	V _{CE} (sat)	I _F =2mA, I _C =0.25mA	_	0.75	1	V
	Rise Time	${ m t_r}$	$V_{\rm CC}=5V,~I_{\rm C}=1{ m mA}$	_	600	_	119
	Fall Time	tf	$R_L = 1k\Omega$	_	500	_	μs

PRODUCT INDICATION



PRECAUTION

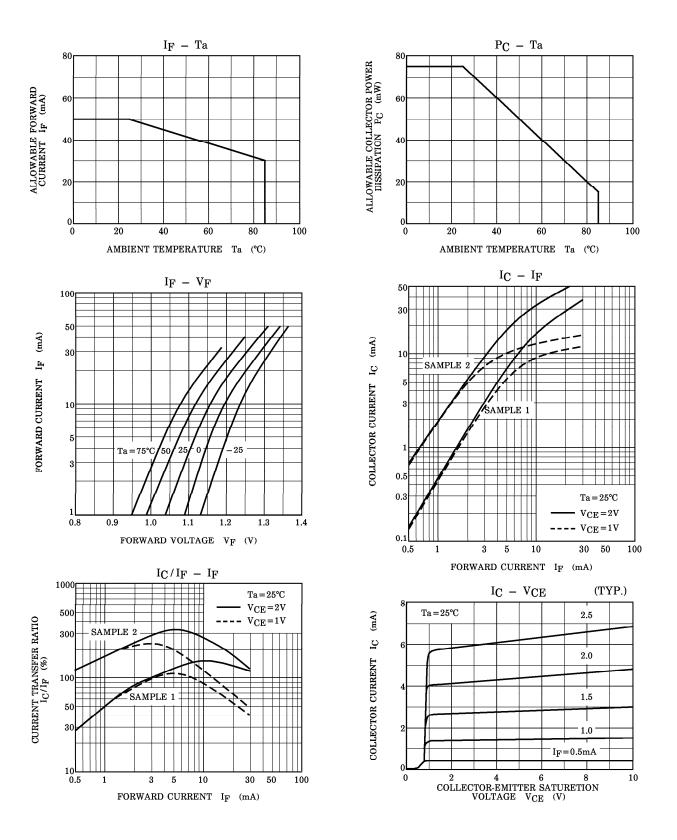
Please be careful of the followings.

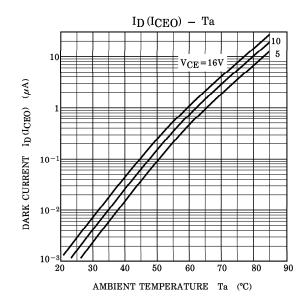
- 1. If chemical are used for cleaning, the soldered surface only shall be cleaned with chemicals avoiding the whole cleaning of the package.
- 2. The container is made of polycarbonate. Polycarbonate is usually stable with acid, alcohol, and aliphatic hydrocarbons however, with pertochemicals (such as benzene, toluene, and acetone), alkali, aromatic hydrocarbons, or chloric hydrocarbons, polycarbonate becomes cracked, swollen, or melted. Please take care when chosing a packaging material by referencing the table below.

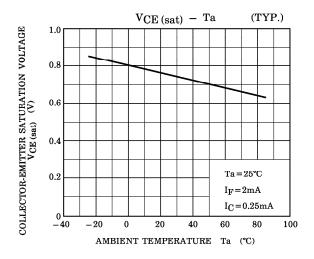
<Chemicals to avoid with polycarbonate>

	PHENOMENON	CHEMICALS	
A	Little deterioration but staining	• nitric acid (low concentration), hydrogen peroxide, chlorine	
В	Cracked, crazed, or swollen	 acetic acid (70% or more) gasoline methyl ethyl ketone, ehtyl acetate, butyl acetate ethyl methacrylate, ethyl ether, MEK acetone, m-amino alcohol, carbon tetrachloride carbon disulfide, trichloroethylene, cresol thinners, oil of turpentine triethanolamine, TCP, TBP 	
C	Melted { }: Used as solvent.	 concentrated sulfuric acid benzene styrene, acrylonitrile, vinyl acetate ethylenediamine, diethylenediamine fchloroform, methyl chloride, tetrachloromethane, dioxane, 1, 2-dichloroethane 	
D	Decomposed	ammonia water other alkali	

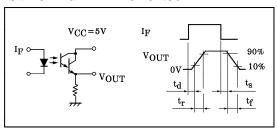
3. TLP863 shall be mounted on an unwarped surface.

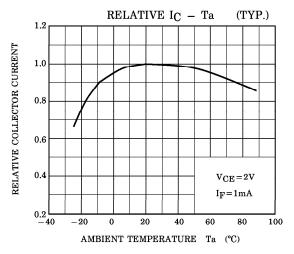


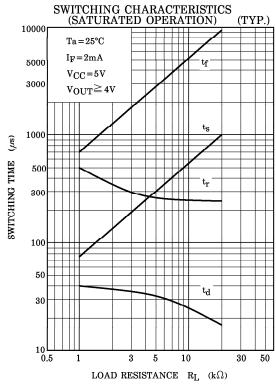


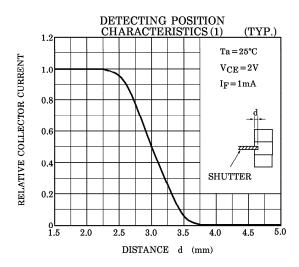


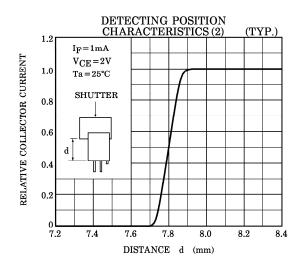
SWITCHING TIME TEST CIRCUIT











POSITIONING OF SHUTTER AND DEVICE

To operate correctly, make sure that the shutter and the device are positioned as shown in the figure below.

The shit pitch of the shutter must be set wider than the slit width of the device.

Determine the width taking the switching time into consideration.

